2812



In re the Application of: KANO et al.

Group Art Unit: 2812

Serial No.: 09/941,982

Examiner: Mulpuri, Savitri

Filed: August 30, 2001

P.T.O. Confirmation No.: 7536

For. METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR LAYER, AND METHOD OF MANUFACTURING NITRIDE-BASED SEMICONDUCTOR

**DEVICE** 

## **AMENDMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Date: May 5, 2004

Sir:

In response to the Office Action dated **November 5, 2003**, please amend the above-identified application as follows: